

# RSS100N03HZG

Nch 30V 10A Power MOSFET

#### Datasheet

| V <sub>DSS</sub>           | 30V    |
|----------------------------|--------|
| R <sub>DS(on)</sub> (Max.) | 13.3mΩ |
| Ι <sub>D</sub>             | ±10A   |
| P <sub>D</sub>             | 2.0W   |

#### Features

- 1) Low on-resistance
- 2) Small Surface Mount Package (SOP8)
- 3) Pb-free plating ; RoHS compliant
- 4) Halogen Free

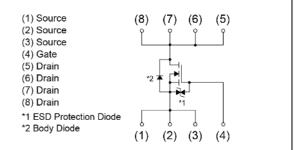
Application

Switching

- 5) Sn100% plating
- 6) AEC-Q101 Qualified

# • Outline SOP8

#### Inner circuit



#### Packaging specifications

|      | Packing         | Embossed<br>Tape |
|------|-----------------|------------------|
|      | Reel size (mm)  | 330              |
| Туре | Tape width (mm) | 12               |
|      | Quantity (pcs)  | 2500             |
|      | Taping code     | ТВ               |
|      | Marking         | RSS100N03        |

#### • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

| Parameter  | Symbol            | Value       | Unit |
|--|-------------------|-------------|------|
| Drain - Source voltage                           | V <sub>DSS</sub>  | 30          | V    |
| Continuous drain current                         | Ι <sub>D</sub>    | ±10         | A    |
| Pulsed drain current                             | 1*1               | ±40         | А    |
| Gate - Source voltage                            | V <sub>GSS</sub>  | ±20         | V    |
| Dower discipation                                | P <sub>D</sub> *2 | 2.0         | W    |
| Power dissipation                                | P <sub>D</sub> *3 | 1.4         | W    |
| Junction temperature                             | T <sub>j</sub>    | 150         | °C   |
| Operating junction and storage temperature range | T <sub>stg</sub>  | -55 to +150 | °C   |

#### •Thermal resistance

| Deremeter                              | Sumbol          | Values |      |      | Unit |
|--|-----------------|--------|------|------|------|
| Parameter                              | Symbol          | Min.   | Тур. | Max. | Unit |
| Thermal registeres junction embient    | $R_{thJA}^{*2}$ | -      | -    | 62.5 | °C/W |
| Thermal resistance, junction - ambient | $R_{thJA}^{*3}$ | -      | -    | 89.2 | °C/W |

#### •Electrical characteristics (T<sub>a</sub> = 25°C)

| Deverseter                                     | Current el                              | Canditiana                                   | Values |      |      | Linit |  |
|--|---|--|--------|------|------|-------|--|
| Parameter                                      | Symbol Conditions                       |  | Min.   | Тур. | Max. | Unit  |  |
| Drain - Source breakdown<br>voltage            | V <sub>(BR)DSS</sub>                    | V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA   | 30     | -    | -    | V     |  |
| Breakdown voltage<br>temperature coefficient   | $\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$ | I <sub>D</sub> = 1mA<br>referenced to 25°C   | -      | 29   | -    | mV/°C |  |
| Zero gate voltage<br>drain current             | I <sub>DSS</sub>                        | V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V  | -      | -    | 1    | μA    |  |
| Gate - Source leakage current                  | I <sub>GSS</sub>                        | $V_{GS}$ = ±20V, $V_{DS}$ = 0V               | -      | -    | ±10  | μA    |  |
| Gate threshold voltage                         | $V_{GS(th)}$                            | V <sub>DS</sub> = 10V, I <sub>D</sub> = 1mA  | 1.0    | -    | 2.5  | V     |  |
| Gate threshold voltage temperature coefficient | $\frac{\Delta V_{GS(th)}}{\Delta T_j}$  | I <sub>D</sub> = 1mA<br>referenced to 25°C   | -      | -1.6 | -    | mV/°C |  |
|  |   | V <sub>GS</sub> = 10V, I <sub>D</sub> = 10A  | -      | 9.5  | 13.3 |       |  |
| Static drain - source<br>on - state resistance | R <sub>DS(on)</sub> *4                  | V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 10A | -      | 12.5 | 17.5 | mΩ    |  |
|  |   | V <sub>GS</sub> = 4.0V, I <sub>D</sub> = 10A | -      | 13.5 | 18.9 |       |  |
| Gate resistance                                | R <sub>G</sub>                          | f = 1MHz, open drain                         | -      | 2.8  | -    | Ω     |  |
| Forward Transfer<br>Admittance                 | Y <sub>fs</sub>   <sup>*4</sup>         | V <sub>DS</sub> = 10V, I <sub>D</sub> = 10A  | 6.0    | -    | -    | S     |  |

\*1 Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

- \*2 Mounted on a ceramic board (30×30×0.8mm)
- \*3 Mounted on a Cu board (40×40×0.8mm)
- \*4 Pulsed



## • Electrical characteristics ( $T_a = 25^{\circ}C$ )

| Deremeter                    | Sumphal               | Conditions                          | Values |      |      | Unit  |  |
|------------------------------|-----------------------|-------------------------------------|--------|------|------|-------|--|
| Parameter                    | Symbol Conditions -   |                                     | Min.   | Тур. | Max. | UTIIL |  |
| Input capacitance            | C <sub>iss</sub>      | V <sub>GS</sub> = 0V                | -      | 1070 | -    |       |  |
| Output capacitance           | C <sub>oss</sub>      | V <sub>DS</sub> = 10V               | -      | 320  | -    | pF    |  |
| Reverse transfer capacitance | C <sub>rss</sub>      | f = 1MHz                            | -      | 200  | -    |       |  |
| Turn - on delay time         | t <sub>d(on)</sub> *4 | $V_{DD} \simeq 15 V, V_{GS} = 10 V$ | -      | 10   | -    |       |  |
| Rise time                    | t <sub>r</sub> *4     | I <sub>D</sub> = 5A                 | -      | 16   | -    | 20    |  |
| Turn - off delay time        | $t_{d(off)}^{*4}$     | $R_L \simeq 3.0\Omega$              | -      | 55   | -    | ns    |  |
| Fall time                    | $t_{f}^{*4}$          | R <sub>G</sub> = 10Ω                | -      | 24   | -    |       |  |

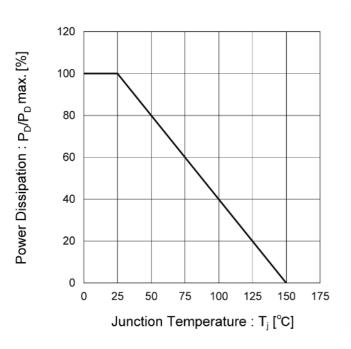
#### • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

| Deremeter            | Symbol Conditions  |                        | Values |      |      | Unit |
|----------------------|--------------------|------------------------|--------|------|------|------|
| Parameter            | Symbol             | Conditions             | Min.   | Тур. | Max. | Unit |
| Total gate charge    | Q <sub>g</sub> *4  | V <sub>DD</sub> ≃ 15V, | -      | 14   | 20   |      |
| Gate - Source charge | Q <sub>gs</sub> *4 | I <sub>D</sub> = 10A,  | -      | 2.7  | -    | nC   |
| Gate - Drain charge  | Q <sub>gd</sub> *4 | V <sub>GS</sub> = 5V   | -      | 5.3  | -    |      |

## •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

| Parameter                  | Sumbol             | Conditions                                  | Values |      |      | Linit |  |
|----------------------------|--------------------|---|--------|------|------|-------|--|
| Farameter                  | Symbol             | Conditions                                  | Min.   | Тур. | Max. | Unit  |  |
| Continuous forward current | ۱ <sub>s</sub>     | T - 25°0                                    | -      | -    | 1.6  | А     |  |
| Pulse forward current      | I <sub>SP</sub> *1 | T <sub>a</sub> = 25°C                       | -      | -    | 6.4  | А     |  |
| Forward voltage            | V <sub>SD</sub> *4 | V <sub>GS</sub> = 0V, I <sub>S</sub> = 6.4A | -      | -    | 1.2  | V     |  |





#### Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area

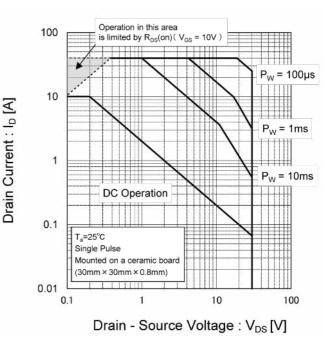
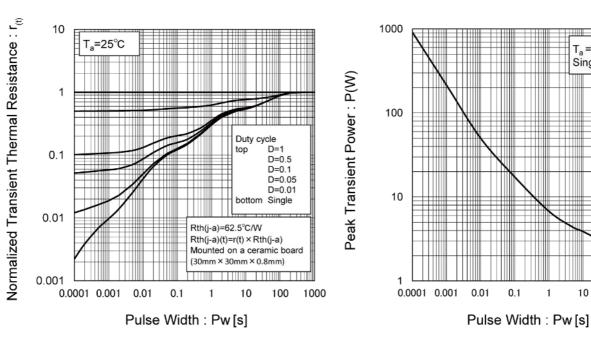


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

Fig.4 Single Pulse Maximum Power Dissipation





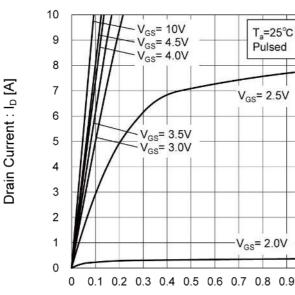
10

100

1000

T<sub>a</sub> = 25°C Single Pulse

#### Electrical characteristic curves



#### Fig.5 Typical Output Characteristics(I)

T<sub>a</sub>=25°C

Pulsed

V<sub>GS</sub>= 2.5V

V<sub>GS</sub>= 2.0V

1

Fig.6 Typical Output Characteristics(II)

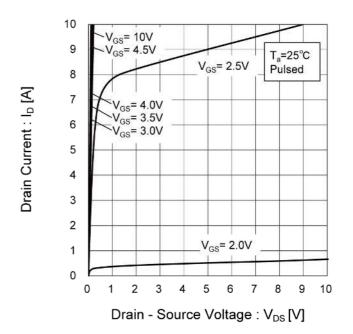
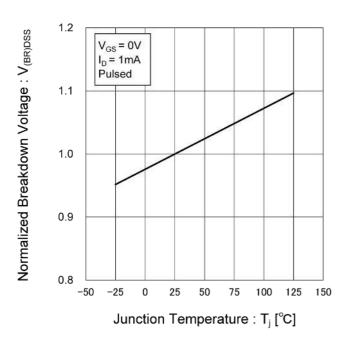


Fig.7 Breakdown Voltage vs. **Junction Temperature** 

Drain - Source Voltage : V<sub>DS</sub> [V]



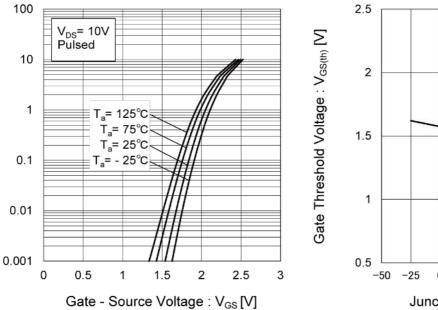


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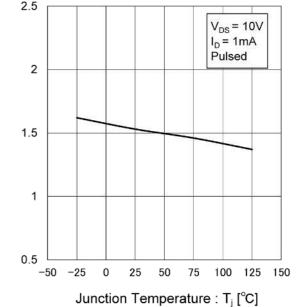


Drain Current : I<sub>D</sub> [A]

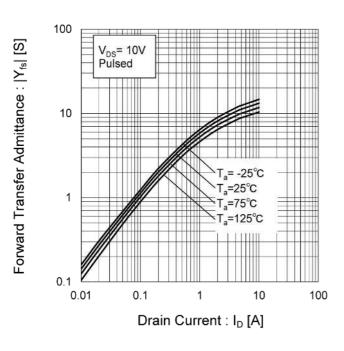
# Fig.8 Typical Transfer Characteristics



#### Fig.9 Gate Threshold Voltage vs. Junction Temperature



#### Fig.10 Forward Transfer Admittance vs. Drain Current





#### • Electrical characteristic curves

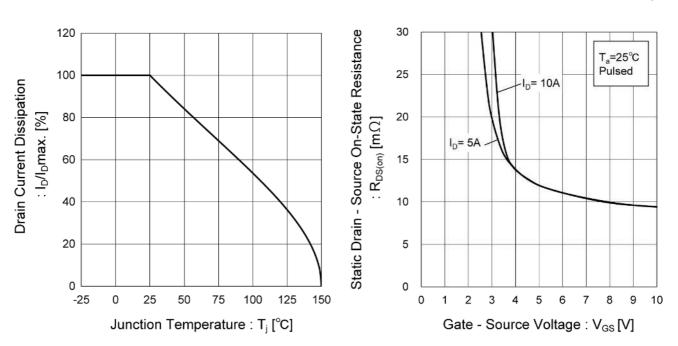
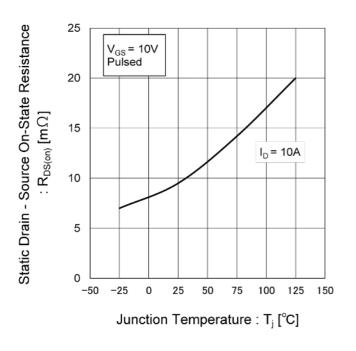


Fig.11 Drain Current Derating Curve

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature





#### Electrical characteristic curves

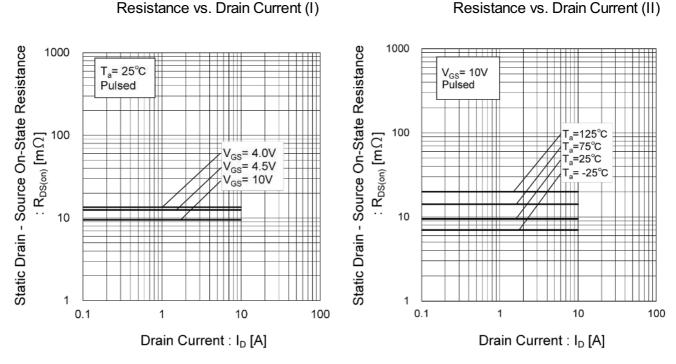


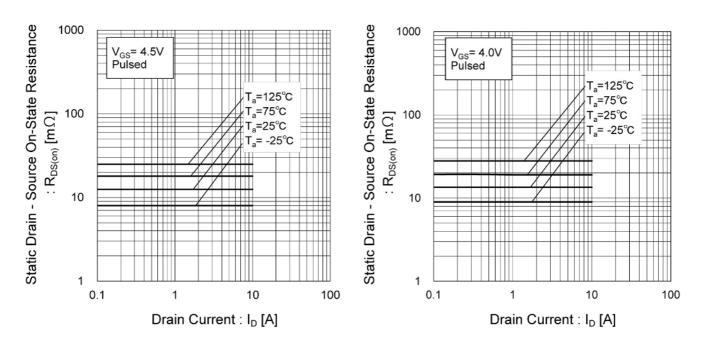
Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I)

Fig.16 Static Drain - Source On - State

Resistance vs. Drain Current (III)

Fig.17 Static Drain - Source On - State Resistance vs. Drain Current (IV)

Fig.15 Static Drain - Source On - State



# Fig.14 Static Drain - Source On - State



#### • Electrical characteristic curves

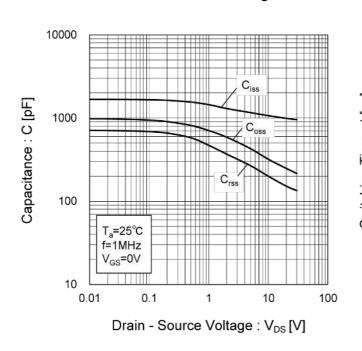


Fig.18 Typical Capacitances vs.

Drain - Source Voltage

Fig.19 Switching Characteristics

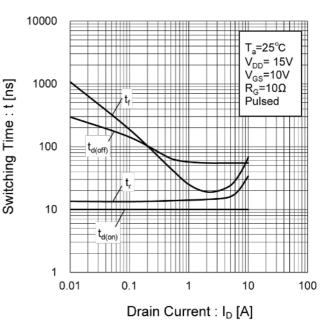


Fig.20 Typical Gate Charge

Gate - Source Voltage : V<sub>GS</sub> [V]

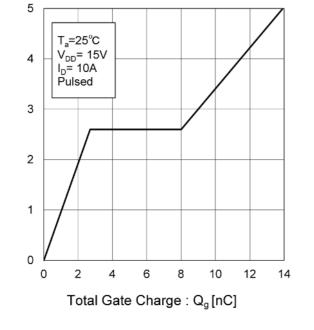
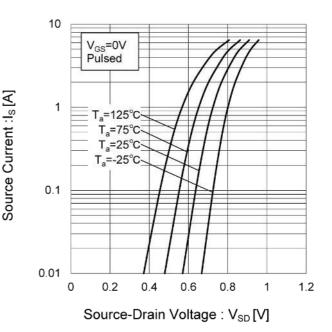


Fig.21 Source Current vs. Source Drain Voltage





#### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

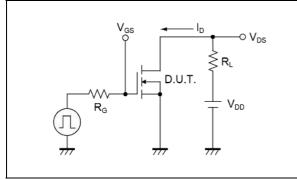


Fig.2-1 Gate Charge Measurement Circuit

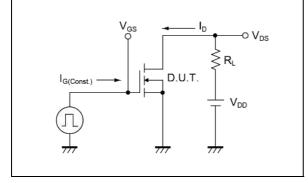
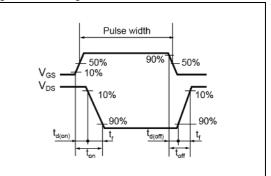
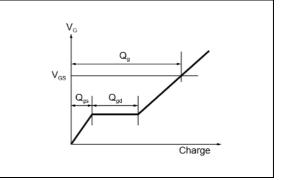


Fig.1-2 Switching Waveforms



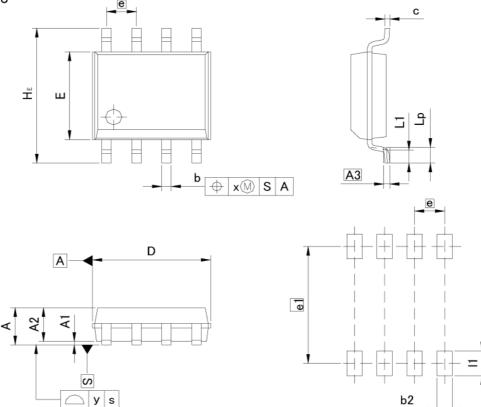






#### Dimensions

SOP8



Pattern of terminal position areas [Not a pattern of soldering pads]

|    | MILIM | ETERS | INC   | HES   |
|----|-------|-------|-------|-------|
|    | MIN   | MAX   | MIN   | MAX   |
| Α  | ÷)    | 1.75  | -     | 0.069 |
| A1 | 0.    | 15    | 0.0   | 06    |
| A2 | 1.40  | 1.60  | 0.055 | 0.063 |
| A3 | 0.    | 25    | 0.0   | 10    |
| b  | 0.30  | 0.50  | 0.012 | 0.020 |
| с  | 0.10  | 0.30  | 0.004 | 0.012 |
| D  | 4.80  | 5.20  | 0.189 | 0.205 |
| E  | 3.75  | 4.05  | 0.148 | 0.159 |
| е  | 1.    | 27    | 0.050 |       |
| HE | 5.70  | 6.30  | 0.224 | 0.248 |
| L1 | 0.40  | 0.60  | 0.016 | 0.024 |
| Lp | 0.65  | 0.85  | 0.026 | 0.033 |
| x  | 0.15  |       | 0.006 |       |
| У  | 0.    | 0.10  |       | 04    |

| DIM | MILIMETERS  |      | INC             | HES   |
|-----|-------------|------|-----------------|-------|
| DIM | MIN         | MAX  | MIN             | MAX   |
| b2  |             | 0.65 | <del></del>     | 0.026 |
| e1  | 5.          | 15   | 0.3             | 203   |
| 11  | <del></del> | 1.15 | <del>77</del> 8 | 0.045 |

Dimension in mm/inches



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| (Note1) Medical Equipment Classification of the Specific Applications |
|---|
|---|

| JAPAN   | USA    | EU         | CHINA   |
|---------|--------|------------|---------|
| CLASSII |        | CLASS II b | CLASSⅢ  |
| CLASSIV | CLASSⅢ | CLASSⅢ     | CLASSII |

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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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